MOSFET - Power, Single N-Channel, WDFN6

30 V, 4.38 mΩ, 18.8 A

NTLJS5D0N03C

Features

- Small Footprint (4 mm²) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- These Devices are Pb-Free, Halogen-Free/BFR-Free and are RoHS Compliant

Applications

- DC-DC Converters
- Wireless Chargers
- Power Load Switch
- Power Management and Protection
- Battery Management

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Parar	neter		Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	30	V
Gate-to-Source Voltage			V _{GS}	±20	V
Continuous Drain Current R _{0.IA}	Steady State	T _A = 25°C	Ι _D	18.8	А
(Notes 1, 3)	Siale	T _A = 85°C		13.5	
Power Dissipation $R_{\theta JA}$ (Notes 1, 3)		$T_A = 25^{\circ}C$	P _D	2.40	W
Continuous Drain Current R _{0.1A}	Steady State	$T_A = 25^{\circ}C$	۱ _D	11.2	А
(Notes 2, 3)	Siale	T _A = 85°C		8.1	
Power Dissipation $R_{\theta JA}$ (Notes 2, 3)		$T_A = 25^{\circ}C$	PD	0.86	W
Pulsed Drain Current	$T_A = 25^{\circ}C$, $t_p = 10 \ \mu s$		I _{DM}	75	А
Operating Junction and Storage Temperature Range			T _J , T _{stg}	–55 to +150	°C
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)		ΤL	260	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS (Note 1)

Parameter	Symbol	Value	Unit
Junction-to-Ambient - Steady State (Note 1)	$R_{\theta JA}$	52	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	145	

1. Surface-mounted on FR4 board using 1 in² pad size, 2 oz. Cu pad.

Surface-mounted on FR4 board using minimum pad size, 2 oz. Cu pad.
The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted. Actual continuous current will be limited by thermal & electro-mechanical application board design. R_{θCA} is determined by the user's board design.

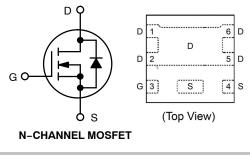


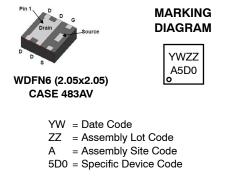
ON Semiconductor®

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V _{(BR)DSS}	R _{DS(on)} MAX	I _D MAX
30 V	4.38 mΩ @ 10 V	18.8 A
	7.25 mΩ @ 4.5 V	10.0 A

ELECTRICAL CONNECTION





ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 4 of this data sheet.

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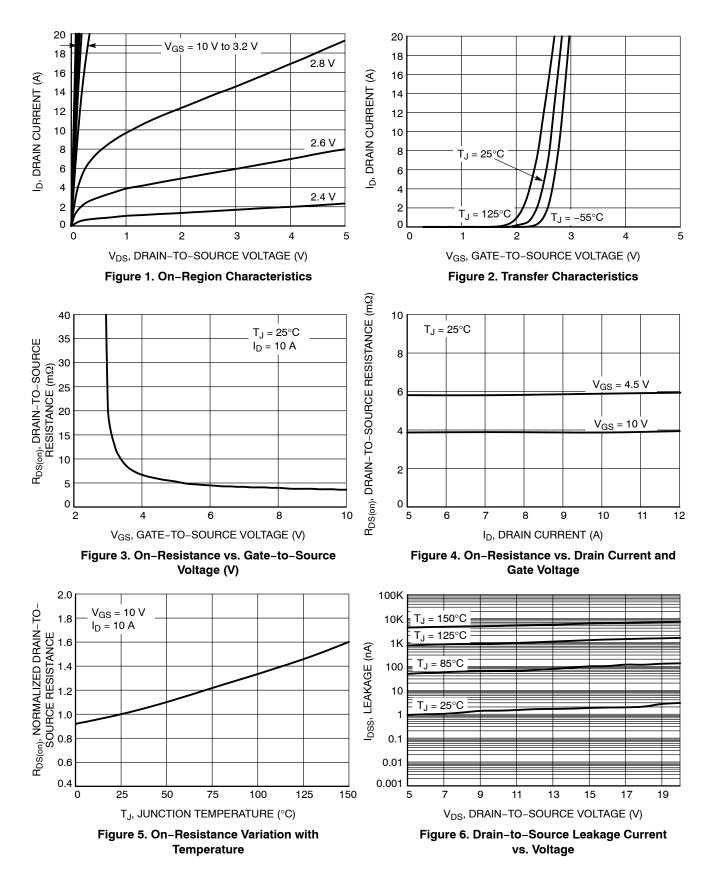
ELECTRICAL CHARACTERISTICS (T_J = $25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS	·				-	-	-
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I _D = 250 µA		30			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} / T _J	$I_D = 250 \ \mu A$, ref to $25^{\circ}C$			18.5		mV/°C
Zero Gate Voltage Drain Current	I _{DSS} V	$V_{GS} = 0 V_{0}$	T _J = 25°C			1	μA
		V _{GS} = 0 V, V _{DS} = 24 V	T _J = 125°C			10	1
Gate-to-Source Leakage Current	I _{GSS}	V_{DS} = 0 V, V_{G}	_S = ±20 V			±100	nA
ON CHARACTERISTICS (Note 4)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_{D}$	= 250 μA	1.2		2.2	V
Threshold Temperature Coefficient	V _{GS} /T _J	I _D = 250 μA, r	ef to 25°C		-5.43		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V,	_D = 10 A		3.94	4.38	mΩ
		V _{GS} = 4.5 V,	I _D = 10 A		5.96	7.25	1
Forward Transconductance	9fs	V _{DS} = 5 V, I	_D = 10 A		44		S
Gate Resistance	R _G	T _A = 25	5°C		0.7		Ω
HARGES AND CAPACITANCES							
Input Capacitance	C _{iss}				1255		pF
Output Capacitance	C _{oss}	V _{GS} = 0 V, V _E f = 1.0 M	_S = 15 V, /Hz		625		
Reverse Transfer Capacitance	C _{rss}				20		
Total Gate Charge	Q _{G(TOT)}	V _{GS} = 4.5 V, V _{DS} = 15 V, I _D = 10 A			8		nC
Threshold Gate Charge	Q _{G(TH)}				2		nC
Gate-to-Source Charge	Q _{GS}				3		
Gate-to-Drain Charge	Q _{GD}				2		
Total Gate Charge	Q _{G(TOT)}	V_{GS} = 10 V, V_{DS} = 15 V, I _D = 10 A			18		nC
SWITCHING CHARACTERISTICS, V	GS = 4.5 V (Note	5)					-
Turn–On Delay Time	t _{d(on)}				12		ns
Rise Time	t _r	V _{GS} = 4.5 V. V	חח = 15 V.		5.5		1
Turn-Off Delay Time	t _{d(off)}	V _{GS} = 4.5 V, V I _D = 10 A, R	$_{\rm G} = 6 \Omega$		16.5		1
Fall Time	t _f				5.7		
SWITCHING CHARACTERISTICS, V	GS = 10 V (Note	5)					
Turn–On Delay Time	t _{d(on)}				8.2		ns
Rise Time	t _r	V _{GS} = 10 V. V.	חר = 15 V.		2.2		1
Turn-Off Delay Time	t _{d(off)}	$\begin{array}{l} V_{GS} = 10 \; V, \; V_{DD} = 15 \; V, \\ I_{D} = 10 \; A, \; R_{G} = 6 \; \Omega \end{array}$			23.2		1
Fall Time	t _f				3.5		1
RAIN-SOURCE DIODE CHARACTE	RISTICS						
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V,	$T_J = 25^{\circ}C$		0.79	1.2	V
		$I_{\rm S} = 10 \rm{A}$	T _J = 125°C		0.65		1
Reverse Recovery Time	t _{RR}	$V_{OO} = 0 V dl_0/dt$	= 100 A/us		31		ns
Reverse Recovery Charge	Q _{RR}	V_{GS} = 0 V, dI _S /dt = 100 A/µs, I _S = 10 A			12.5		nC

performance may not be indicated by the Electrical Characteristics for the listed test conditions. 4. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%. 5. Switching characteristics are independent of operating junction temperatures.

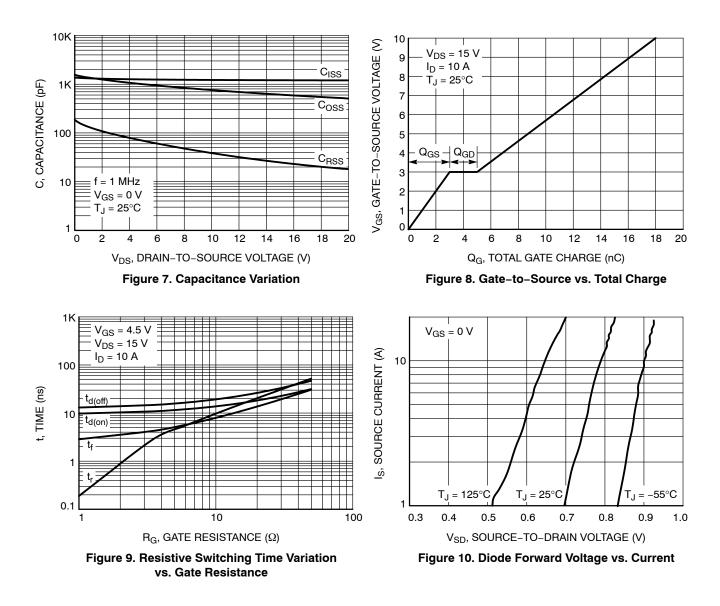
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TYPICAL CHARACTERISTICS



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TYPICAL CHARACTERISTICS

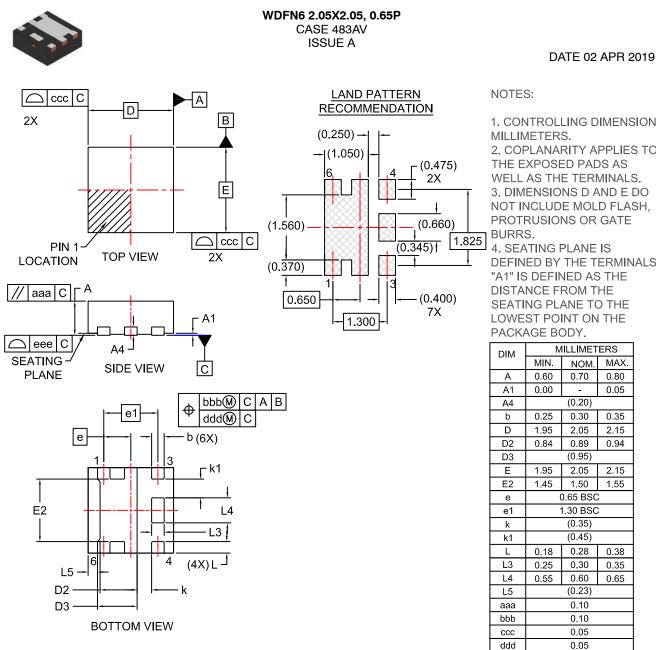


DEVICE ORDERING INFORMATION

Device	Package	Shipping [†]
NTLJS5D0N03CTAG	WDFN6 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





1. CONTROLLING DIMENSION:

2. COPLANARITY APPLIES TO THE EXPOSED PADS AS WELL AS THE TERMINALS. 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE

4. SEATING PLANE IS DEFINED BY THE TERMINALS. "A1" IS DEFINED AS THE DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.

DIM	MILLIMETERS			
	MIN.	NOM.	MAX.	
A	0.60	0.70	0.80	
A1	0.00	-	0.05	
A4		(0.20)		
b	0.25	0.30	0.35	
D	1.95	2.05	2.15	
D2	0.84	0.89	0.94	
D3	(0.95)			
E	1.95 2.05		2.15	
E2	1.45	1.50	1.55	
е	0.65 BSC			
e1	1.30 BSC			
k	(0.35)			
k1	(0.45)			
L	0.18	0.28	0.38	
L3	0.25	0.30	0.35	
L4	0.55	0.60	0.65	
L5	(0.23)			
aaa	0.10			
bbb	0.10			
ccc	0.05			
ddd	0.05			
eee	0.05			

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